



Vishay Semiconductors

Schottky Rectifier, 1.0 A





PRODUCT SUMMARY				
Package	DO-214AA (SMB)			
I _{F(AV)}	1 A			
V_R	90 V, 100 V			
V _F at I _F	0.78 V			
I _{RM}	1 mA at 125 °C			
T _J max.	175 °C			
Diode variation	Single die			
E _{AS}	1.0 mJ			

FEATURES

- Small foot print, surface mountable
- Low forward voltage drop



- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

The VS-MBRS190TRPbF, VS-MBRS1100TRPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	1.0	Α	
V _{RRM}		90/100	V	
I _{FSM}	t _p = 5 μs sine	870	Α	
V _F	1.0 Apk, T _J = 125 °C	0.63	V	
TJ	Range	- 55 to 175	°C	

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBRS190TRPbF	VS-MBRS1100TRPbF	UNITS	
Maximum DC reverse voltage	V _R	90	100	V	
Maximum working peak reverse voltage	V_{RWM}	90			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 147 °C, rectangular waveform		1.0	
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	870	Α
	IFSM	10 ms sine or 6 ms rect. pulse		50	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 0.5		А	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM} ⁽¹⁾	V _{FM} ⁽¹⁾ 1 A	T _J = 25 °C	0.78	V
See fig. 1	VFM (*)	1 A	T _J = 125 °C	0.62	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.5	- mA
See fig. 2	IRM (*)	T _J = 125 °C		1.0	
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		42	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 55 to 175	°C	
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation See fig. 4	36	°C AM	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W	
Approximate weight			0.10	g	
Approximate weight			0.003	OZ.	
Marking device		Case style SMB (similar to DO-214AA)	V19/	V19/V10	

Notes

⁽¹⁾ $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

⁽²⁾ Mounted 1" square PCB

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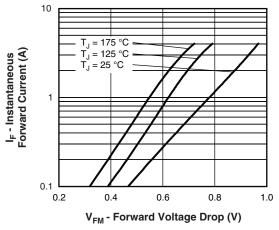


Fig. 1 - Maximum Forward Voltage Drop Characteristics

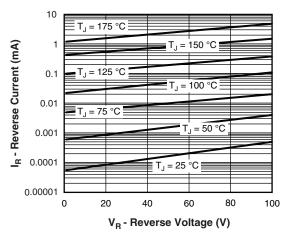


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

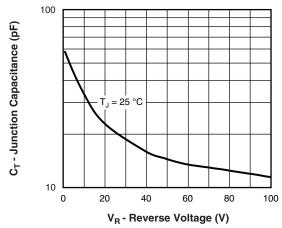


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

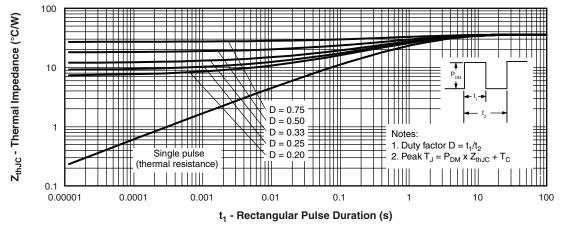


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

VS-MBRS190TRPbF, VS-MBRS1100TRPbF

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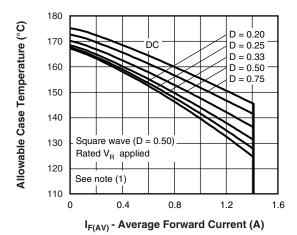


Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

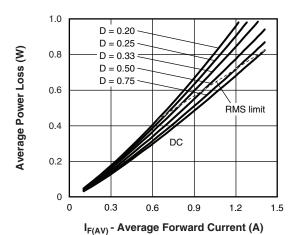


Fig. 6 - Maximum Average Forward Dissipation vs.

Average Forward Current

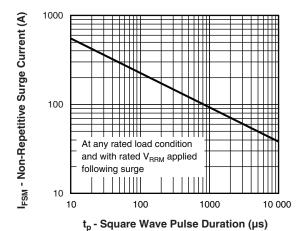


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R



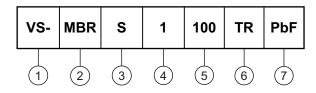
VS-MBRS190TRPbF, VS-MBRS1100TRPbF

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product suffix

2 - Schottky MBR series

3 - S = SMB

Current rating (1 = 1 A)

90 = 90 V 100 = 100 V

6 - TR = Tape and reel (3000 pieces)

7 - PbF = Lead (Pb)-free

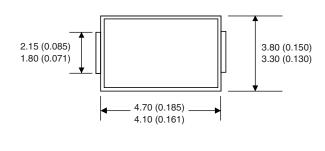
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95017			
Part marking information	www.vishay.com/doc?95029			
Packaging information	www.vishay.com/doc?95034			

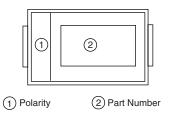


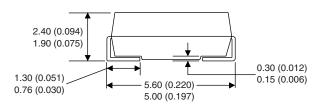
Vishay High Power Products

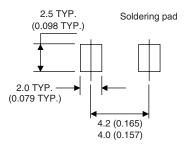
SMB

DIMENSIONS in millimeters (inches)











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